



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)	
	0.027 at V _{GS} = - 4.5 V	- 7		
- 20	0.035 at $V_{GS} = -2.5 \text{ V}$	- 6.2	21	
	0.048 at V _{GS} = - 1.8 V	- 5.2		

Ordering Information: Si3493DV-T1-E3 (Lead (Pb)-free)

Si3493DV-T1-GE3 (Lead (Pb)-free and Halogen-free)

Marking Code: 93xxx

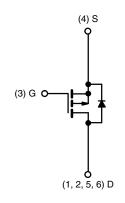
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET: 1.8 V Rated
- Ultra-Low On-Resistance
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

- Load Switch
- PA Switch
- · Battery Switch



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Dunin Comment /T 150 °C) a	T _A = 25 °C	I _D	- 7	- 5.3		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 3.6	- 3.9		
Pulsed Drain Current		I _{DM}	- 20		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9		
	T _A = 25 °C	P _D	2.0	1.1	W	
Maximum Power Dissipation ^a	T _A = 85 °C		1.0	0.6		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular landing to Austriant	t ≤ 5 s	R _{thJA}	45	62.5	°C/W
Maximum Junction-to-Ambient ^a	Steady State		90	110	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	25	30	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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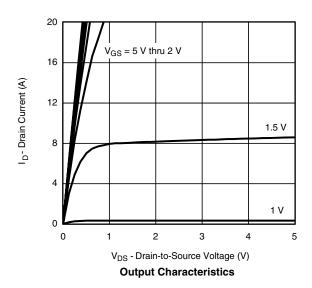
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions M		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 0.40		- 1	V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1	— uA	
		V_{DS} = - 20 V, V_{GS} = 0 V, T_J = 85 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 20			Α	
		V _{GS} = - 4.5 V, I _D = - 7 A		0.022	0.027		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 6.2 A		0.029	0.035	Ω	
		V _{GS} = - 1.8 V, I _D = - 3 A		0.039	0.048		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 7 A		25		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.7	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			21	32		
Gate-Source Charge	Q_{gs} $V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -7 \text{ A}$		2.6		nC		
Gate-Drain Charge	Q_{gd}			6			
Turn-On Delay Time	t _{d(on)}			20	30		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		40	60	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 4.5 V, $R_g=$ 6 Ω		125	190		
Fall Time	t _f			85	130		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -1.7 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		64	90		

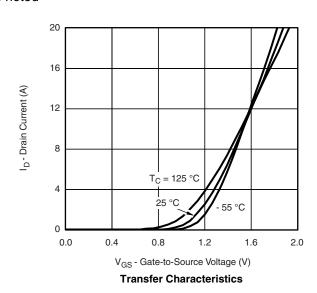
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



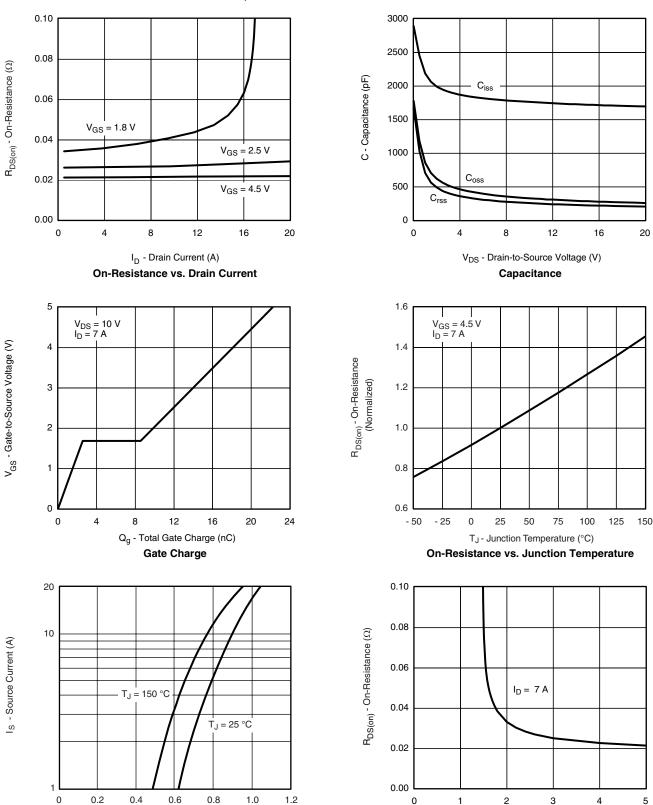








TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

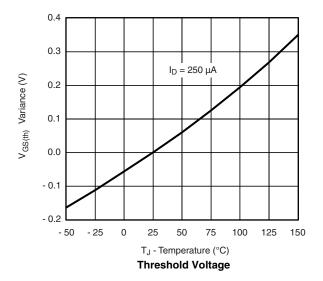
V_{GS} - Gate-to-Source Voltage (V)

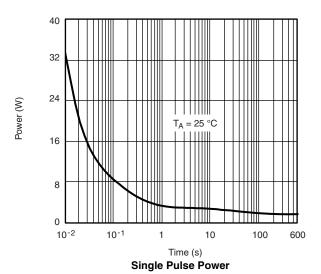
On-Resistance vs. Gate-to-Source Voltage

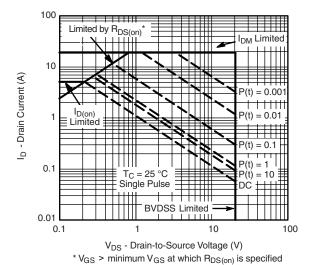
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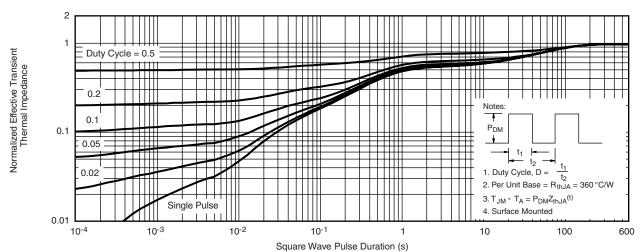
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





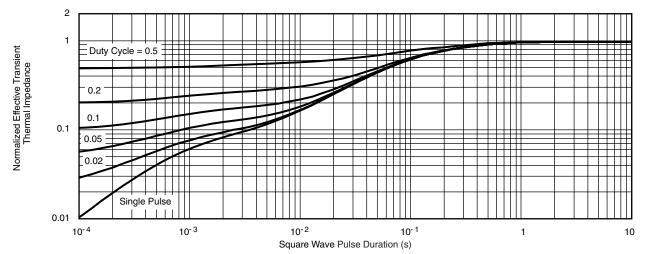


Safe Operating Area





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71936.



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